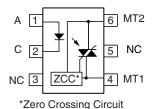


## Vishay Semiconductors

# Optocoupler, Phototriac Output, Zero Crossing





#### **DESCRIPTION**

The BRT21, BRT22, BRT23 product family consists of AC switch optocouplers with zero voltage detectors with two electrically insulated lateral power ICs which integrate a thyrister system, a photo detector and noise suppression at the output and an IR GaAs diode input.

High input sensitivity is achieved by using an emitter follower phototransistor and a SCR predriver resulting in an LED trigger current of less than 2 mA or 3 mA (DC). Inverse parallel SCRs provide commutating dV/dt greater than 10 kV/ $\mu$ s.

The zero cross line voltage detection circuit consists of two MOSFETS and a photodiode.

The BRT21/22/23 product family isolates low-voltage logic from 120, 230, and 380 VAC lines to control resistive, inductive or capacitive loads including motors, solenoids, high current thyristers or TRIAC and relays.

#### **FEATURES**

- High input sensitivity I<sub>FT</sub> = 1.0 mA
- I<sub>TRMS</sub> = 300 mA
- High static dV/dt 10 000 V/μs
- Electrically insulated between input and output circuit



· Microcomputer compatible

- Trigger current
  - (I<sub>FT</sub> < 1.2 mA) BRT22F, BRT23F,</li>
  - (I<sub>FT</sub> < 2 mA) BRT21**H**, BRT22**H**, BRT23**H**
  - (I<sub>FT</sub> < 3 mA) BRT21**M**, BRT22**M**, BRT23**M**
- · Available surface mount and on on tape and reel
- · Zero voltage crossing detector
- UL file E52744 system code J
- DIN EN 60747-5-5 available with option 1
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **APPLICATIONS**

- · Industrial controls
- · Office equipment
- · Consumer appliances

ORDER INFORMATION					
PART	REMARKS				
BRT21H	$V_{DRM} \le 400 \text{ V, DIP-6, I}_{FT} = 2.0 \text{ mA}$				
BRT21M	$V_{DRM} \le 400 \text{ V, DIP-6, I}_{FT} = 3.0 \text{ mA}$				
BRT22F	$V_{DRM} \le 600 \text{ V, DIP-6, I}_{FT} = 1.2 \text{ mA}$				
BRT22H	$V_{DRM} \le 600 \text{ V, DIP-6, I}_{FT} = 2.0 \text{ mA}$				
BRT22M	$V_{DRM} \le 600 \text{ V}, \text{ DIP-6}, I_{FT} = 3.0 \text{ mA}$				
BRT23F	$V_{DRM} \le 800 \text{ V, DIP-6, I}_{FT} = 1.2 \text{ mA}$				
BRT23H	$V_{DRM} \le 800 \text{ V, DIP-6, I}_{FT} = 2.0 \text{ mA}$				
BRT23M	$V_{DRM} \le 800 \text{ V, DIP-6, I}_{FT} = 3.0 \text{ mA}$				
BRT21H-X006	$V_{DRM} \le 400 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 2.0 \text{ mA}$				
BRT21H-X007	$V_{DRM} \le 400 \text{ V}$ , SMD-6 (option 7), $I_{FT} = 2.0 \text{ mA}$				
BRT21M-X006	$V_{DRM} \le 400 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 3.0 \text{ mA}$				
BRT22F-X006	$V_{DRM} \le 600 \text{ V}$ , SMD-6 (option 7), $I_{FT} = 1.2 \text{ mA}$				
BRT22H-X007	$V_{DRM} \le 600 \text{ V}$ , SMD-6 (option 7), $I_{FT} = 2.0 \text{ mA}$				
BRT22M-X006	$V_{DRM} \le 600 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 3.0 \text{ mA}$				
BRT23F-X006	$V_{DRM} \le 800 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 1.2 \text{ mA}$				
BRT23F-X007	$V_{DRM} \le 800 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 1.2 \text{ mA}$				
BRT23H-X006	$V_{DRM} \le 800 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 2.0 \text{ mA}$				
BRT23H-X007	$V_{DRM} \le 800 \text{ V}$ , SMD-6 (option 7), $I_{FT} = 2.0 \text{ mA}$				
BRT23M-X006	$V_{DRM} \le 800 \text{ V}$ , DIP-6 400 mil (option 6), $I_{FT} = 3.0 \text{ mA}$				
BRT23M-X007	$V_{DRM} \le 800 \text{ V}$ , SMD-6 (option 7), $I_{FT} = 3.0 \text{ mA}$				

#### Note

For additional information on the available options refer to option information.

## **BRT21/BRT22/BRT23**

## Vishay Semiconductors

## Optocoupler, Phototriac Output, Zero Crossing



ABSOLUTE MAXIMUM RAT	'INGS <sup>(1)</sup>				
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT		•		1	
Reverse voltage	I <sub>R</sub> = 10 μA		V <sub>R</sub>	6.0	V
Forward current			I <sub>F</sub>	60	mA
Surge current			I <sub>FSM</sub>	2.5	Α
Power dissipation			P <sub>diss</sub>	100	mW
Derate from 25 °C				1.33	mW/°C
OUTPUT					
		BRT21	$V_{DM}$	400	V
Peak off-state voltage	$I_{D(RMS)} = 70 \mu A$	BRT22	$V_{DM}$	600	V
	, ,	BRT23	$V_{DM}$	800	V
RMS on-state current			I <sub>TM</sub>	300	mA
Single cycle surge current				3.0	Α
Power dissipation			P <sub>diss</sub>	600	mW
Derate from 25 °C				6.6	mW/°C
COUPLER					
Isolation test voltage (between emitter and detector, climate per DIN 500414, part 2, Nov. 74)	t = 1.0 min		V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Pollution degree (DIN VDE 0109)				2	
Creepage distance				≥ 7.0	mm
Clearance distance				≥ 7.0	mm
Comparative tracking index per DIN IEC 112/VDE 0303 part 1, group IIIa per DIN VDE 6110			СТІ	≥ 175	
Landa d'anno antidana a	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C		R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
Isolation resistance	$V_{IO}$ = 500 V, $T_{amb}$ = 100 °C		R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Storage temperature range			T <sub>stg</sub>	- 40 to + 100	°C
Ambient temperature range			T <sub>amb</sub>	- 40 to + 100	°C
Soldering temperature (2)	$\begin{array}{l} \text{max.} \leq 10 \text{ s dip soldering} \\ \geq 0.5 \text{ mm from case bottom} \end{array}$		T <sub>sld</sub>	260	°C

#### Notes

<sup>(2)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I <sub>F</sub> = 10 mA	V <sub>F</sub>		1.16	1.35	V	
Reverse current	V <sub>R</sub> = 6 V	I <sub>R</sub>		0.1	10	μΑ	
Capacitance	$f = 1 MHz, V_F = 0 V$	Co		25		pF	
Thermal resistance, junction to ambient		R <sub>thJA</sub>		750		K/W	

 $<sup>^{(1)}</sup>$  T<sub>amb</sub> = 25  $^{\circ}$ C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.



## Optocoupler, Phototriac Output, Zero Crossing

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PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
ОИТРИТ					•	
Off-state voltage	$I_{D(RMS)} = 70 \mu A$	V <sub>D(RMS)</sub>	424	460		V
Repetitive peak off-state voltage	I <sub>DRM</sub> = 100 μA	$V_{DRM}$	600			V
Off-state current	$V_D = V_{DRM}, T_{amb} = 100 \text{ °C},$ $I_F = 0 \text{ mA}$	I <sub>D(RMS)</sub>		10	100	μΑ
On-state voltage	I <sub>T</sub> = 300 mA	$V_{TM}$		1.7	3.0	V
On-state current	PF = 1.0, V <sub>T(RMS)</sub> = 1.7 V	I <sub>TM</sub>			300	mA
Surge (non-repetitive), on-state current	f = 50 Hz	I <sub>TSM</sub>			3.0	Α
Trianger oursent temp are dient		$\Delta I_{FT1}/\Delta T_{j}$		7.0	14	μA/K
Trigger current temp. gradient		$\Delta I_{FT2}/\Delta T_{j}$		7.0	14	μA/K
Inhibit voltage temp. gradient		$\Delta V_{DINH}/\Delta T_{j}$		- 20		mV/K
Off-state current in inhibit state	$I_F = I_{FT1}, V_{DRM}$	I <sub>DINH</sub>		50	200	μΑ
Holding current		I <sub>H</sub>		65	500	μΑ
Latching current	V <sub>T</sub> = 2.2 V	ΙL		5.0		mA
Zero cross inhibit voltage	$I_F = \text{rated } I_{FT}$	V <sub>IH</sub>		15	25	V
Turn-on time	$V_{RM} = V_{DM} = V_{D(RMS)}$	t <sub>on</sub>		35		μs
Turn-off time	PF = 1.0, I <sub>T</sub> = 300 mA	t <sub>off</sub>		50		μs
Critical rate of rise of off-state	$V_D = 0.67 \ V_{DRM}, \ T_j = 25 \ ^{\circ}C$	dV/dt <sub>cr</sub>	10000			V/µs
voltage	$V_D = 0.67 \ V_{DRM}, \ T_j = 80 \ ^{\circ}C$	dV/dt <sub>cr</sub>	5000			V/μs
Critical rate of rise of voltage at current commutation	$V_D = 0.67 V_{DRM}$ , $dI/dt_{crq} \le 15 A/ms$ , $T_j = 25 °C$	dV/dt <sub>crq</sub>	10000			V/µs
	$V_D = 0.67 V_{DRM}$ , $dI/dt_{crq} \le 15 A/ms$ , $T_j = 80 °C$	dV/dt <sub>crq</sub>	5000			V/µs
Critical rate of rise of on-state		dl/dt <sub>cr</sub>	8.0			A/μs
Thermal resistance, junction to ambient		R <sub>thJA</sub>		125		K/W
COUPLER						
Critical rate of rise of coupled input/output voltage	$I_T = 0 A$ , $V_{RM} = V_{DM} = V_{D(RMS)}$	dV <sub>IO</sub> /dt		10000		V/μs
Common mode coupling capacitance		C <sub>CM</sub>		0.01		pF
Capacitance (input to output)	f = 1.0 MHz, V <sub>IO</sub> = 0 V	C <sub>IO</sub>		0.8		pF
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>is</sub>		≥ 10 <sup>12</sup>		Ω
isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>is</sub>		≥ 10 <sup>11</sup>		Ω
	V <sub>D</sub> = 5.0 V, F - versions	I <sub>FT</sub>			1.2	mA
Trigger current	V <sub>D</sub> = 5.0 V, H - versions	I <sub>FT</sub>			2.0	mA
	V <sub>D</sub> = 5.0 V, M - versions	I <sub>FT</sub>			3.0	mA

 $T_{amb} = 25$  °C, unless otherwise specified. Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

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SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				40/100/21			
Comparative tracking index		CTI	175		399		
V <sub>IOTM</sub>			6000			V	
V <sub>IORM</sub>			630			V	
P <sub>SO</sub>					200	mW	
I <sub>SI</sub>					400	mA	
T <sub>SI</sub>					175	°C	
Creepage distance	standard DIP-6		7			mm	
Clearance distance	standard DIP-6		7			mm	
Creepage distance	400 mil DIP-6		8			mm	
Clearance distance	400 mil DIP-6		8			mm	

#### Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

#### **POWER FACTOR CONSIDERATIONS**

A snubber is not needed to eliminate false operation of the TRIAC driver because of the high static and commutating dV/dt with loads between 1.0 and 0.8 power factors. When inductive loads with power factors less than 0.8 are being driven, include a RC snubber or a single capacitor directly across the device to damp the peak commutating dV/dt spike. Normally a commutating dV/dt causes a turning-off device to stay on due to the stored energy remaining in the turning-off device.

But in the case of a zero voltage crossing optotriac, the commutating dV/dt spikes can inhibit one half of the TRIAC from turning on. If the spike potential exceeds the inhibit voltage of the zero cross detection circuit, half of the TRIAC will be heldoff and not turn-on. This hold-off condition can be eliminated by using a snubber or capacitor placed directly across the optotriac as shown in Figure 1. Note that the value of the capacitor increases as a function of the load current. The hold-off condition also can be eliminated by providing a higher level of LED drive current. The higher LED drive provides a larger photocurrent which causes the phototransistor to turn-on before the commutating spike has activated the zero cross network. Figure 2 shows the relationship of the LED drive for power factors of less than 1.0. The curve shows that if a device requires 1.5 mA for a resistive load, then 1.8 times 2.7 mA) that amount would be required to control an inductive load whose power factor is less than 0.3.

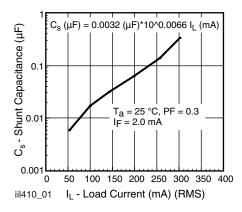


Fig. 1 - Shunt Capacitance vs. Load Current

## Optocoupler, Phototriac Output, Zero Crossing

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#### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

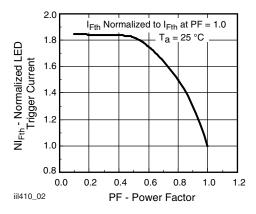


Fig. 2 - Normalized LED Trigger Current vs. Power Factor

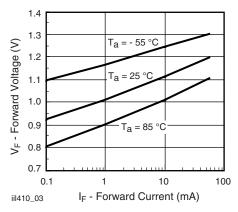


Fig. 3 - Forward Voltage vs. Forward Current

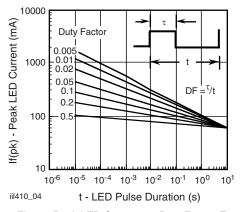


Fig. 4 - Peak LED Current vs. Duty Factor, Tau

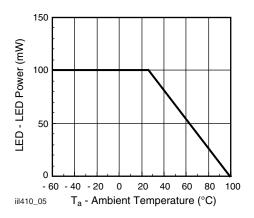


Fig. 5 - Maximum LED Power Dissipation

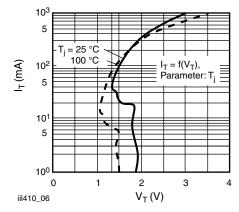


Fig. 6 - Typical Output Characteristics

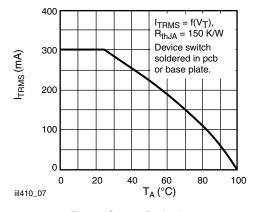


Fig. 7 - Current Reduction

## Vishay Semiconductors

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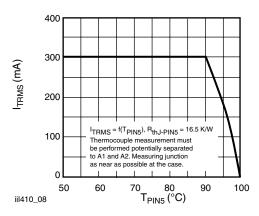


Fig. 8 - Current Reduction

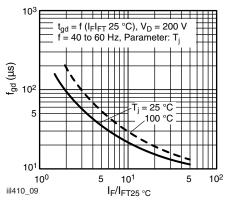


Fig. 9 - Typical Trigger Delay Time

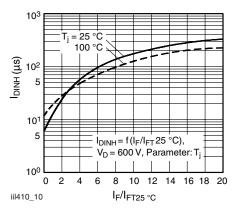


Fig. 10 - Typical Inhibit Current

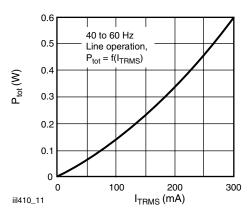


Fig. 11 - Power Dissipation 40 to 60 Hz Line Operation

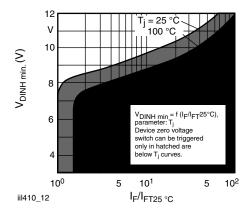
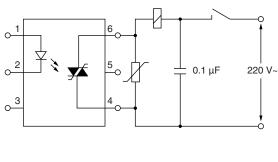


Fig. 12 - Typical Static Inhibit Voltage Limit



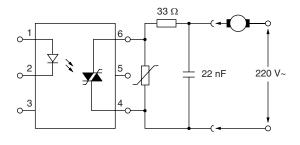
iil410\_13

Fig. 13 - 1- Apply a Capacitor to the Supply Pins at the Load-Side



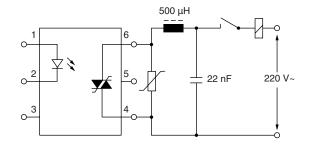
## Optocoupler, Phototriac Output, Zero Crossing

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iil410\_14

Fig. 14 - 2 - Connect a Series Resistor to the Output and Bridge Both by a Capacitor



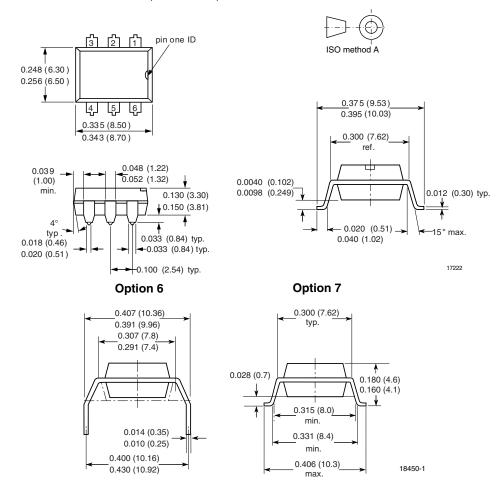
iil410\_15

Fig. 15 - 3 - Connect a Choke of Low Winding Cap. in Series, e.g., a Ringcore Choke, with Higher Load Currents

#### **TECHNICAL INFORMATION**

See Application Note for additional information.

#### **PACKAGE DIMENSIONS** in inches (millimeters)



### BRT21/BRT22/BRT23

Vishay Semiconductors

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#### **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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